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AMENDMENTS TO THE CLAIMS

- 1. (Currently Amended) A lumped-element diplexer implemented in a multi-layered substrate comprising:
- a low-pass filter circuit wherein circuit elements are disposed on a first series of layers of the multi-layered substrate and wherein a first end of the low-pass filter circuit is connected to a first port and a second end of the low-pass filter circuit is connected to a second port;
 - a high-pass filter circuit wherein circuit elements are disposed on a second series of layers of the multi-layered substrate and wherein a first end of the high-pass filter circuit is connected to [[a]] the first port and a second end of the high-pass filter circuit is connected to a third port; and
 - a ground plane forming a base of the multi-layered substrate, wherein elements of the filter circuits are orientated horizontally with respect to the ground plane and are arranged in layers aligned substantially vertically, these layers being separated by a dielectric material and inter-layer connections being implemented by at least a via;

wherein <u>no layer is between</u> an uppermost layer of the first series of layers of the multi-layered substrate is immediately adjacent to <u>and</u> a lowermost layer of the second series of layers of the multi-layered substrate.

2. (Cancelled)

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3. (Currently Amended) The lumped-element diplexer implemented in a multi-layered substrate of claim 1, wherein:

the low-pass filter circuit comprises:

a first capacitor plate disposed on a first layer of the multi-layered substrate; a second capacitor plate disposed on a second layer of the multi-layered

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substrate; and

a first inductor plate directly disposed on a third layer of the multi-layered substrate;

wherein the first capacitor plate is connected to the first port, the second capacitor plate is connected to a first end of the first inductor plate and the second port via a third capacitor plate of the high-pass filter circuit, and a second end of the first inductor plate is connected to the first port; and

the high-pass filter circuit comprises:

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- a third capacitor plate disposed on a forth fourth layer of the multi-layered substrate;
 - a fourth capacitor plate disposed on a fifth layer of the multi-layered substrate;
 - a fifth capacitor plate disposed on a sixth layer of the multi-layered substrate; and
 - a second inductor plate directly disposed on a seventh layer of the multi-layered substrate;
 wherein the third capacitor plate is connected to the second port, the forth fourth capacitor plate is connected to a first end of the second inductor plate, the fifth capacitor plate is connected to the third port and a second end of the second inductor plate is connected to the ground
- 4. (Currently Amended) The lumped-element diplexer implemented in a multi-layered substrate of claim 1, wherein inductive the circuit elements of the filter circuits comprise inductive elements that comprise plates formed as spirals.
 - 5. (Currently Amended) The lumped-element diplexer implemented in a multi-layered

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substrate of claim 1, wherein the circuit elements of the filter circuits comprise at least one inductive element of the filter-circuits is formed on a plurality of layers of the multi-layered substrate.

- 6. (Currently Amended) The lumped-element diplexer implemented in a multi-layered substrate of claim 1, wherein at least one capacitive element of the circuit elements of the filter circuits comprises comprise at least one capacitive element comprising a plurality of plates formed on a plurality of layers of the multi-layered substrate.
- 7. (Original) The lumped-element diplexer implemented in a multi-layered substrate of claim I, wherein the high-pass filter circuit further comprises a low frequency notch filter circuit.
- 8. (Currently Amended) The lumped-element diplexer implemented in a multi-layered substrate of claim [[7]] 3, wherein at least the third and fifth capacitor plates are dimensioned to have additional overlapping area in order to realize an additional capacitor equivalence.
- 9. (Currently Amended) The lumped-element diplexer implemented in a multi-layered substrate of claim 1, wherein the ground <u>plane</u> forms a zeroth layer of the lumped-element diplexer.
 - 10. (Original) The lumped-element diplexer implemented in a multi-layered substrate of claim 1, wherein the device is realized in a multi-layered, low temperature co-fired ceramic substrate.
 - 11. (Currently Amended) A lumped-element diplexer implemented in a multi-layered substrate comprising:

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a low-pass filter circuit comprising:

- a first capacitor plate disposed on a first layer of a first series of layers of the multi-layered substrate;
- a second capacitor plate disposed on a second layer of [[a]] the first series of layers of the multi-layered substrate; and
- a first inductor plate directly disposed on a third layer of [[a]] the first series of layers of the multi-layered substrate;

wherein the first capacitor plate is connected to a first port, the second capacitor plate is connected to a first end of the first inductor plate and to a second port via a third capacitor plate of a high-pass filter circuit of the lumped-element diplexer, and a second end of the first inductor plate is connected to the first port; and

a high-pass filter circuit comprising:

- a third capacitor plate disposed on a first layer of a second series of layers of the multi-layered substrate;
- a fourth capacitor plate disposed on a second layer of [[a]] the second series of layers of the multi-layered substrate;
- a fifth capacitor plate disposed on a third layer of [[a]] the second series of layers of the multi-layered substrate; and
- a second inductor plate directly disposed on a forth fourth layer of [[a]] the second series of layers of the multi-layered substrate;

wherein the third capacitor plate is connected to the second port, the forth fourth capacitor plate is connected to a first end of the second inductor plate, the fifth capacitor plate is connected to a third port and a second end of the second inductor plate is connected to a ground plane of the lumped-element diplexer, and wherein the high-pass filter circuit further comprises a low frequency notch filter circuit realized by additional overlapping area of the third and fifth capacitor plates.

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- a ground plane forming a base of the multi-layered substrate, wherein elements of the filter circuits are orientated horizontally with respect to the ground plane and are arranged in layers aligned substantially vertically, these layers being separated by a dielectric material and inter-layer connections being implemented by at least a via;
- wherein no layer is between an uppermost layer of the first series of layers of the multi-layered substrate is-immediately adjacent to and a lowermost layer of the second series of layers of the multi-layered substrate.
- 10 12. (Cancelled)

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- 13. (Currently Amended) The lumped-element diplexer implemented in a multi-layered substrate of claim 11, wherein inductive elements of the filter circuits comprise-plates formed as spirals an inductor plate comprises a spiral-shaped metal strip.
- 14. (Currently Amended) The lumped-element diplexer implemented in a multi-layered substrate of claim 11, wherein further comprising at least one inductive element of the filter-circuits is formed on a plurality of layers of the multi-layered substrate.
- 15. (Currently Amended) The lumped-element diplexer implemented in a multi-layered substrate of claim 11, wherein further comprising at least one capacitive element of the filter circuits comprises a plurality of plates formed on a plurality of layers of the multi-layered substrate.
- 25 16. (Currently Amended) The lumped-element diplexer implemented in a multi-layered substrate of claim 11, wherein the ground <u>plane</u> forms a zeroth layer of the lumped-element diplexer.